GE1117A

1A Low Dropout Positive Adjustable or Fixed-Mode Regulator

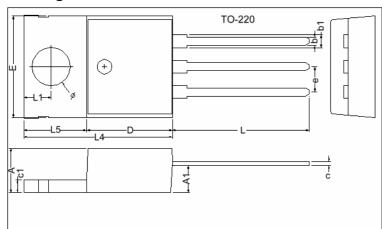
Description

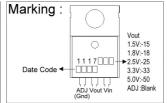
The GE1117A is a low dropout at positive adjustable or fixed-mode regulator with minimum of 1A output current capability. The product is specifically designed to provide well-regulated supply for low voltage IC applications such as high-speed bus termination and low current 3.3V logic supply. GE1117A is also well suited for other applications such as VGA cards. GE1117A is guaranteed to have lower than 1.4V dropout at full load current making it ideal to provide well-regulated outputs of 1.25 to 5.0 with 6.4V to 12V input supply.

Features

- 1.4Vmaximum dropout full load current
- Fast transient response
- Output current limiting
- Built-in thermal shutdown
- · Good noise rejection
- 3-Terminal Adjustable or Fixed 1.5V,1.8V,2.5V,3.3V,5.0V

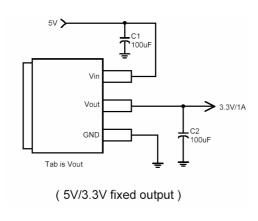
Package Dimensions

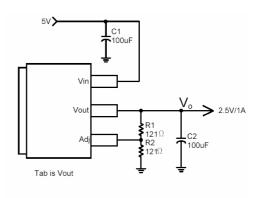




REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	rLi.	Min.	Max.	
Α	4.40	4.80	c1	1.25	1.45	
b	0.76	1.00	b1	1.17	1.47	
С	0.36	0.50	L	13.25	14.25	
D	8.60	9.00	е	2.54 REF.		
Е	9.80	10.4	L1	2.60	2.89	
L4	14.7	15.3	Ø	3.71	3.96	
L5	6.20	6.60	A1	2.60	2.80	

Typical Circuit



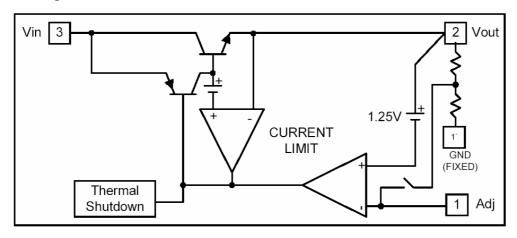


(5V/2.5V ADJ output)

Note:
$$V_o = V_{REF} * (1 + \frac{R_2}{R_1})$$

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Block Diagram



Pin Descriptions

Name	I/O	Pin#	Function
Adj (GND)		1	A resistor divider from this pin to the Vout pin and ground sets the output voltage (Ground only for fixed mode)
Vout	0	2	The output of the regulator. A minimum of 10uF capacitor must be connected from this pin to ground to insure stability.
Vin	I		The input pin of regulator. Typically a large storage capacitor is connected from this pin to ground to insure that the input voltage does not sag below the minimum dropout voltage during the load transient response. This pin must always be 1.3V higher than Vout in order for the device to regulate properly.

Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
Vin	DC Supply Voltage	-0.3 to 12	V
PD	Power Dissipation	Internally Limited	
TST	Storage Temperature	-65 ~ + 150	$^{\circ}\!\mathbb{C}$
TOP	Operating Junction Temperature Range	0 ~ + 150	$^{\circ}\!\mathbb{C}$

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Electrical Characteristics

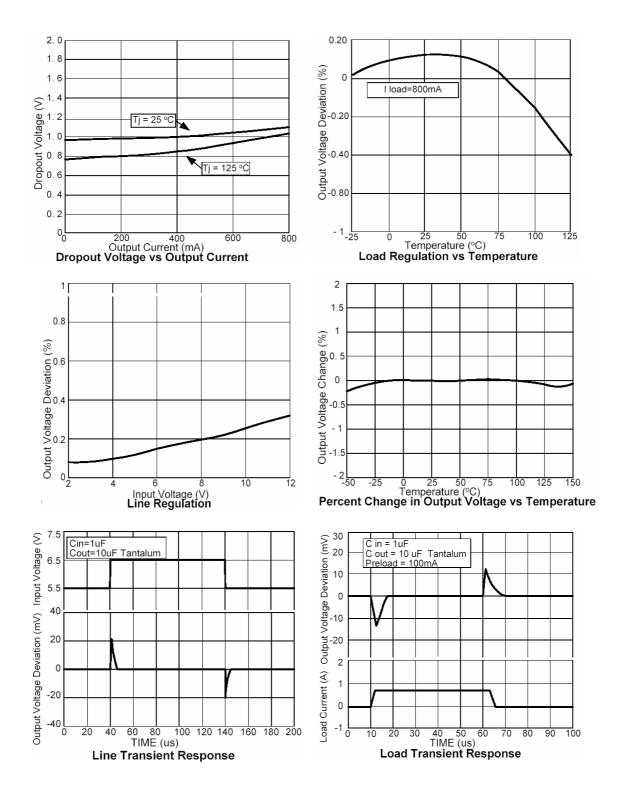
Parameter	Conditions		MIN	TYP	MAX	UNIT
Reference Voltage	GE1117AADJ	lo=10mA, Tj=25°C, (Vin-Vout)=1.5V	1.225	1.250	1.275	V
	GE1117A-1.5	Io=10mA, Tj=25°C, 3.0V≤Vin≤12V		1.500	1.530	V
	GE1117A-1.8	Io=10mA, Tj=25°C, 3.3V≤Vin≤12V		1.800	1.836	V
Output Voltage	GE1117A-2.5	.5 Io=10mA, Tj=25°C, 4.0V≤Vin≤12V		2.500	2.550	V
	GE1117A-3.3	Io=10mA, Tj=25°C, 4.8V≤Vin≤12V		3.300	3.365	V
	GE1117A-5.0	Io=10mA, Tj=25°C, 6.5V≤Vin≤12V		5.000	5.100	V
Line Regulation	GE1117A-XXX	Io=10mA, Vout+1.5V <vin<12v, tj="25°C</td"><td>-</td><td>-</td><td>0.2</td><td>%</td></vin<12v,>	-	-	0.2	%
	GE1117AADJ	Vin=3.3V, Vadj=0, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>-</td><td>1</td><td>%</td></lo<1a,>	-	-	1	%
	GE1117A-1.5	Vin=3.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>12</td><td>15</td><td>mV</td></lo<1a,>	-	12	15	mV
Load Degulation	GE1117A-1.8	-1.8 Vin=3.3V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>15</td><td>18</td><td>mV</td></lo<1a,>		15	18	mV
Load Regulation	GE1117A-2.5	Vin=4.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>20</td><td>25</td><td>mV</td></lo<1a,>	-	20	25	mV
	GE1117A-3.3	Vin=5.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>26</td><td>33</td><td>mV</td></lo<1a,>	-	26	33	mV
	GE1117A-5.0	Vin=8.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>40</td><td>50</td><td>mV</td></lo<1a,>	-	40	50	mV
Dropout Voltage (VIN-VOUT)	GE1117A-XXX	lo=1A, (ΔVout=0.1% Vout)	-	1.3	1.4	V
Current Limit	GE1117A-XXX	Vin-Vout=5V	1.1	-	-	Α
Minimum Load Current	Adjustable model	Vin=5V	-	5	10	mA
Adjust Pin Current	Adjustable model	Vin=12V, Io=10mA	-	50	100	uA
Quiescent Current	fixed model	Vin=12V, Io=0mA	-	-	12	mA
Thermal Regulation	Ta=25°C,30ms pulse		-	0.008	0.04	%/W
Dinale Dejection	F=120HZ,Cout=25uF Tantalum, Iout=1A					
Ripple Rejection	GE1117A-XXX	VIN=VOUT+3V	-	60	70	dB
Temperature Stability	perature Stability Io=10mA		-	0.5	-	%
θJA Thermal Resistance Junction-to-Ambient(No heat sink ;No air flow)			-	85	-	°C/W
Outrol Circuitry/Power Transistor Control Circuitry/Power Transistor		-	0.65/2.7	-	°C/W	

Note 1: See thermal regulation specifications for changes in output voltage due to heating effects. Line and load regulation are measured at a constant junction Temperature by low duty cycle pulse testing. Load regulation is measured at the output lead =1/18" from the package.

Note 2: Line and load regulation are guaranteed up to the maximum power dissipation of 15W. Power dissipation is determined by the difference in input and output and the output current. Guaranteed maximum power dissipation will not be available over the full input/output range.

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Characteristics Curve



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Taiwan: No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C. TEL: 886-3-597-7061 FAX: 886-3-597-9220, 597-92785

China: (201203) No.255, Jang-Jiang Tsai-Lueng RD., Pu-Dung-Hsin District, Shang-Hai City, China TEL: 86-21-5895-7671 ~ 4 FAX: 86-21-38950165

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